



isc Silicon NPN Power Transistor

DESCRIPTION

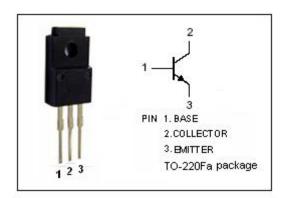
- · Low Collector Saturation Voltage
 - : V_{CE(sat)}= 0.4V(Max)@ I_C= 3A
- Complement to Type 2SA1388
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

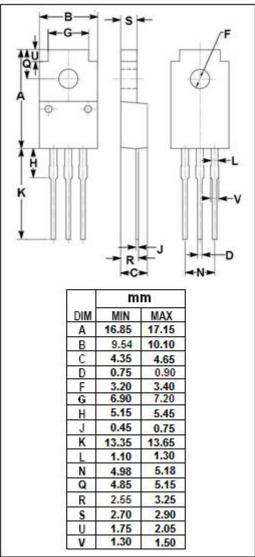
APPLICATIONS

Designed for high current switching applications

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	100	V	
Vceo	Collector-Emitter Voltage	80	V	
V _{EBO}	Emitter-Base Voltage	7	V	
lc	Collector Current-Continuous 5		А	
Ісм	Collector Current-Peak 8		Α	
l _Β	Base Current-Continuous 1 A		Α	
P _C	Collector Power Dissipation @ T _C =25°C	25	W	
	Collector Power Dissipation @ T _a =25℃	2	VV	
TJ	Junction Temperature	150 °C		
T _{stg}	Storage Temperature Range -55~150		°C	





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2SC3540

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA; I _B = 0	80			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 3A; I _B = 0.15A			0.4	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 3A; I _B = 0.15A			1.2	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 100V; I _E = 0			1	μ А
I _{EBO}	Emitter Cutoff Current	V _{EB} = 7V; I _C = 0			1	μА
h _{FE-2}	DC Current Gain	I _C = 1A; V _{CE} = 1V	70		240	
h _{FE-3}	DC Current Gain	I _C = 3A; V _{CE} = 1V	40			
f⊤	Current-Gain—Bandwidth Product	I _C = 1A; V _{CE} = 4V		120		MHz
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} = 1.0MHz		80		pF
Switching times						
ton	Turn-on Time			0.2		μ S
t _{stg}	Storage Time	I_{B1} = - I_{B2} = 0.15A; R_L = 10 Ω ; V_{CC} \approx 30V		1.0		μ s
t _f	Fall Time			0.1		μ s

♦ h_{FE-1} classifications

0	Y		
70-140	120-240		

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